

# UTC UNISONIC TECHNOLOGIES CO., LTD

1N4007G **DIODE** 

# GLASS PASSIVATED SILICON RECTIFIER

# **DESCRIPTION**

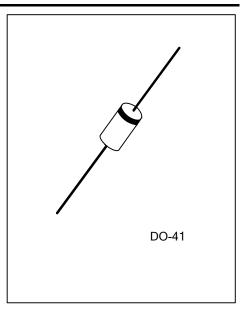
The UTC 1N4007G is a glass passivated silicon rectifier, it uses UTC's advanced technology to provide customers with high forward surge current and low reverse leakage, etc.

# **FEATURES**

- \* Low reverse leakage
- \* High forward surge current capability

# **SYMBOL**





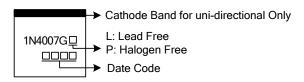
# **ORDERING INFORMATION**

Ordering Number		Dardens	Pin Assignment		Danking	
Lead Free	Halogen Free	Package	1	2	Packing	
1N4007GL-Z41-R	1N4007GP-Z41-R	DO-41	K	Α	Tape Reel	

Note: Pin Assignment: A: Anode K: Cathode



# **MARKING**



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# ■ ABSOLUTE MAXIMUM RATINGS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

PARAMETER	SYMBOL	RATINGS	UNIT
Working Peak Reverse Voltage	$V_{RWM}$	1000	V
Repetitive Peak Reverse Voltage	$V_{RRM}$	1000	V
Maximum RMS Reverse Voltage	$V_{RMS}$	700	V
DC Blocking Voltage	$V_R$	1000	V
Average Rectified Output Current (T <sub>A</sub> =105°C)	Io	1.0	Α
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>	30	Α
Junction Temperature	T <sub>J</sub>	-55~+150	°C
Storage Temperature	T <sub>STG</sub>	-55~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

# **■ THERMAL DATA**

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient (Note 2)	θιΔ	50	°C/W

# **■ ELECTRICAL CHARACTERISTICS**

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

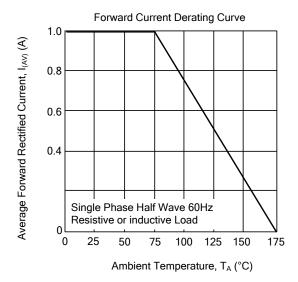
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Instantaneous Forward Voltage	V <sub>FM</sub>	I <sub>F</sub> =1.0A			1.1	V
DC Reverse Current at Rated DC Blocking		T <sub>A</sub> =25°C			5.0	μA
Voltage	I <sub>RM</sub>	T <sub>A</sub> =100°C			50.0	μA
Junction Capacitance (Note 1)	CJ			15.0		pF

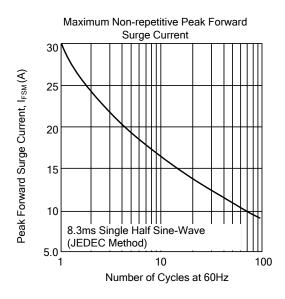
Notes: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

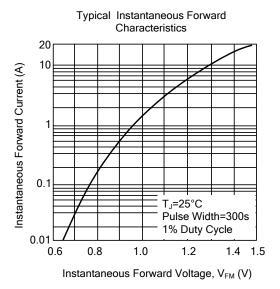
2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted.

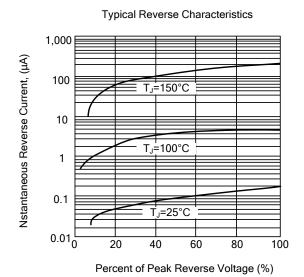
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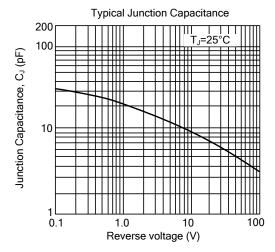
# **■ TYPICAL CHARACTERISTICS**

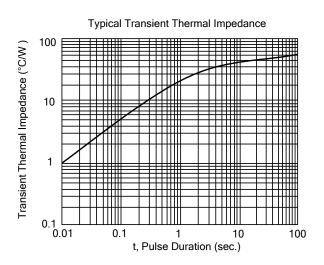












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